

L Number	Hits	Search Text	DB	Time stamp
5	55	((((power r bus or signal) n ar2 lin) sam ((drive r driver r driving) r (tft or (thin n ar film n ar transist r))) same (activ near matrix)).ti,ab, lm. and ((power r bus or signal) near2 line).ti,ab,clm. and (((power or bus or signal) near2 line) near10 (cover or covered or covering or bury or buried or burying)).ti,ab,clm.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/05/11 12:36
6	6	((((power or bus or signal) near2 line) same ((drive or driver or driving) or (tft or (thin near film near transistor))) same (active near matrix)).ti,ab,clm. and ((power or bus or signal) near2 line).ti,ab,clm. and (((power or bus or signal) near2 line) near10 (cover or covered or covering or bury or buried or burying)).ti,ab,clm. and (voltage near2 drop)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/05/11 12:37
7	3	((((power or bus or signal) near2 line) same ((drive or driver or driving) or (tft or (thin near film near transistor))) same (active near matrix)).ti,ab,clm. and ((power or bus or signal) near2 line).ti,ab,clm. and (((power or bus or signal) near2 line) near10 (cover or covered or covering or bury or buried or burying)).ti,ab,clm. and (voltage near2 drop) and (line near5 resistance)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/05/11 12:38
8	4	((((power or bus or signal) near2 line) same ((drive or driver or driving) or (tft or (thin near film near transistor))) same (active near matrix)).ti,ab,clm. and ((power or bus or signal) near2 line).ti,ab,clm. and (((power or bus or signal) near2 line) near10 (cover or covered or covering or bury or buried or burying)).ti,ab,clm. and (voltage near2 drop) and (line near10 resistance)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/05/11 12:39
9	0	((((power or signal or bus) near2 line) near10 resistance) and (volgate near2 drop) and (active near matrix).ti,ab,clm. and ((power or signal or bus) near2 line).ti,ab,clm.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/05/11 12:41
10	39	((((power or signal or bus) near2 line) near10 resistance) and (voltage near2 drop) and (active near matrix).ti,ab,clm. and ((power or signal or bus) near2 line).ti,ab,clm.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/05/11 12:42
11	10	((((power or signal or bus) near2 line) near10 resistanc) and (v ltage near2 dr p) and (active near matrix).ti,ab,clm. and ((p wer r signal or bus) near2 lin).ti,ab, lm. and (line near10 (bury r buried or burying or ver r c v red or c vering)).ti,ab,clm.	USPAT; US-P PUB; EPO; JPO; DERWENT; IBM_TDB	2004/05/11 12:43

12	3	((p w r or signal or bus) near2 lin) n ar10 resistan e) and (v ltag near2 dr p) and (active near matrix).ti,ab,clm. and ((power or signal r bus) n ar2 lin).ti,ab,clm. and (line n ar10 (bury r buried or burying r ver r v r d or overing)).ti,ab, lm. and power.ti,ab,clm.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/05/11 12:44
13	17	(power near2 line).clm. and (power near2 line).ab. and (active near matrix).clm. and (active near matrix).ab.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/05/11 12:45
14	17	((bus or signal or power) near2 line).clm. and (power near2 line).ab. and (active near matrix).clm. and (active near matrix).ab.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/05/11 12:45
15	252	((bus or signal or power) near2 line).clm. and ((bus or signal or power) near2 line).ab. and (active near matrix).clm. and (active near matrix).ab.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/05/11 12:45
16	17	((bus or signal or power) near2 line).clm. and ((bus or signal or power) near2 line).ab. and (active near matrix).clm. and (active near matrix).ab. and driver.clm. and driver.ab.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/05/11 12:46
17	1	((bus or signal or power) near2 line).clm. and ((bus or signal or power) near2 line).ab. and (active near matrix).clm. and (active near matrix).ab. and driver.clm. and driver.ab. and (line near10 (cover or covered or covering or bury or buried or burying)).clm.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/05/11 12:47
18	0	((bus or signal or power) near2 line).clm. and ((bus or signal or power) near2 line).ab. and (active near matrix).clm. and (active near matrix).ab. and driver.clm. and driver.ab. and (line near10 (cover or covered or covering or bury or buried or burying) near10 (insulating or dielectric or resin or epoxy or organic)).clm.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/05/11 12:48
19	0	((bus or signal or power) near2 line).clm. and ((bus or signal or power) near2 line).ab. and (active near matrix).clm. and (active near matrix).ab. and (tft or (thin near film near transistor) or driver).clm. and driver.ab. and (line near10 (cov r r v red r c v ring r bury r buried r burying) near10 (insulating r diel ctric or resin r epoxy r rgani)). lm.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/05/11 12:48

20	7	((bus r signal r pow r) near2 line).clm. and ((bus r signal r p wer) near2 lin).ab. and (a tive n ar matrix).clm. and (a tive near matrix).ab. and (tft r (thin near film near transistor) r driv r). lm. and (line near10 (cover or c ver d or covering r bury or buried or burying) near10 (insulating or dielectric or resin or epoxy or organic)).clm.	USPAT; US-P PUB; EPO; JPO; DERWENT; IBM_TDB	2004/05/11 12:49
21	5	((bus or signal or power) near2 line).clm. and ((bus or signal or power) near2 line).ab. and (active near matrix).clm. and (active near matrix).ab. and (tft or (thin near film near transistor) or driver).clm. and (line near10 (cover or covered or covering or bury or buried or burying) near10 (insulating or dielectric or resin or epoxy or organic)).clm. and ((voltage near2 drop) or resistance)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/05/11 12:49